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First-principles investigation for some physical properties of some fluoroperovskites compounds ABF_3 (A = K, Na; B = Mg, Zn)

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Abstract: In this work, the structural, electronic and optical properties of fluoroperovskite ABF₃ (A = K, Na; B = Mg, Zn) were studied using two different approaches: the full-potential linearized augmented plane wave method and the pseudo-potential plane wave scheme in the frame of generalized gradient approximation features such as the lattice constant, bulk modulus and its pressure derivative are reported. The ground state properties of these compounds such as the equilibrium lattice constant and the bulk modulus are in good agreement with the experimental results. The first principles calculations were performed to study the electronic structures of ABF₃(A = K, Na; B = Mg, Zn) compounds and the results indicated that these four compounds are indirect band gap insulators. The optical properties are analysed and the source of some peaks in the spectra is discussed. Besides, the dielectric function, refractive index and extinction coefficient for radiation up to 25 eV have also been reported and discussed.

Keywords: Fluoroperovskite; FP-LAPW; PP-PW; Electronic structure; Optical properties

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1. Introduction

Numerous investigations have been extensively done regarding the cubic perovskites with different compositions and structures, motivated by their possible applications in numerous industrial and engineering domains [1–4]. They have shown a wide range of attractive properties ferroelectricity [5, 6], piezoelectricity [7, 8], semiconductivity [9], catalytic activity [10], thermoelectricity [11], superconductivity and metal–insulator transition [12]. As an example ternary oxides of rare earth (Eu, Gd, Tb)CoO₃ type oxides, this series reveal extensive applications in materials science and technology, some of the perovskites (Eu, Gd, Tb)CoO₃ compounds are used as electrode materials for magneto hydrodynamic (MHD)generators [13], for fuel cells [14], half-metallic [15]. On the other

Complex fluorides have unique characteristics in optoelectronic, and luminescent properties and also show various interesting structures [21, 22]. Among them, especially ternary fluorides with perovskite structure, $KXF_3(X = Mg, Ca, Mn, Fe, Co, Ni, and Zn)$, have been in the limelight in these days and have been actively researched due to their high-temperature super-ionic behavior and physical properties, such as piezoelectric characteristics, ferromagnetic, antiferromagnetic, non-magnetic insulator behavior and so on [23–27]. Darabont et al. [28] investigated the $KMgF_3$ single crystals by X-ray diffraction and suggested that these crystals have a cubic perovskite

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hand, perovskites like BaMnO₃ and SrMnO₃have attracted interest in NO removal process as catalysts [16–18]. Earlier works [19, 20] performed on oxide and semiconductor systems showed that the thickness of the metal slab becomes important in determining the electronic structure. A surface energy is converged quickly with increasing number of atomic layers.

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structure with one molecule per unit cell, with lattice parameter $a=3.978\pm0.05\text{\AA}$. The structures and phase transitions in the solid solution $Na_{1-x}K_xMgF_3$ have been investigated recently by Zhao [29] and by Chakhmouradian et et al. [30]. Basically, NaMgF₃ perovskite was first synthesized by Ludekens and Welch [31] before natural NaMgF₃ was discovered by Chao et al. [32], where several experimental and theoretical studies have been reported [30, 33–36]. Generally,perovskites crystallize in orthorhombic structure, but many studies havede picted the cubic one [37–42].

The considered ABF₃ (A = K, Na; B = Mg, Zn) are presumed to have ideal cubic perovskite structure (#221) The cubic unit cell contains one molecule with the Wychoff positions of the atoms are A 1a (0, 0, 0), B 1b (0.5, 0.5, 0.5) and F 3c (0.5, 0.5, 0) In the present paper, the structural, electronic and optic for ABF₃(A = K, Na; B = Mg, Zn) compounds are reported. The aim of this work is to examine the electronic band structure of ABF₃ (A = K, Na; B = Mg, Zn) with emphasis on its derived properties.

The calculations are performed using Full-relativistic (FP-LAPW) and the norm-conserving pseudo potential

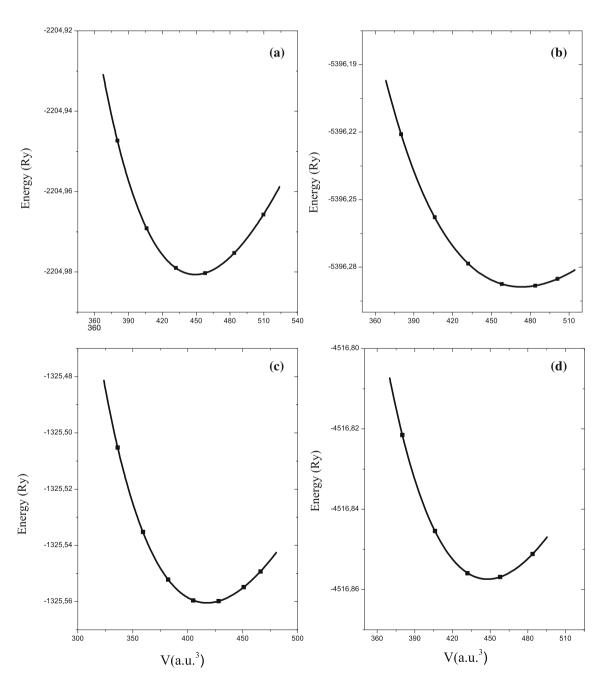


Fig. 1 Calculated total energy as a function of volume, (a) KMgF₃, (b) KZnF₃, (c) NaMgF₃ and (d) NaZnF₃

Table 1 Lattice constant a(A), bulk modulus B (in GPa) pressure derivative of bulk modulus B' and energy gap Eg for $ABF_3(A = K, Na; B = Mg, Zn)$ compounds

	Present work (FP-LAPW)	Present work (PW-PP)	Experiment	Other
KMgF ₃				
a	4.052	4.133	3.978 ± 0.05 [28]	3.91 [53]
			3.9897 [30], 3.9839 [36]	4.0809 [54]
			3.973 [52], 4.0060 [54]	4.040 [59]
			3.993 [55]	
<i>B''</i>	67.53	81.564	71.2 [54],70.4 [56]	90.97 [53]
			75.1 [57], 75.6 [58]	72.01 [54]
				72.15 [59]
B'	4.422	_	4.7 [54]	4.64 [53]
				4.65 [54]
				4.68 [59]
Eg	7.37	7.56	12.4 [25]	7.03 [59]
NaMgF ₃				
a	3.955	4.109	3.955 [32], 3.833 [60]	3.836 [62]
			3.876 [61], 3.964 [70]	3.840 [63]
				3.872 [64]
B	69.87	159.423	66. 8676 [70]	87.999 [<mark>62</mark>]
				78.2 [64]
B'	4.146	_	_	3.97 [64]
Eg	6.40	6.39	_	5.90 [64]
				5.99 [70] ^a
				6.74 [70] ^b
				10.6 [70] ^c
$KZnF_3$				
a	4.124	4.241	4.05 [65], 4.056 [66]	-
			4.0611 [67]	
B	71.463	38.391	_	_
B'	4.50	-	_	_
Eg	4.06	4.43	_	_
$NaZnF_3$				
a	4.049	4.182	4.065 [70]	_
B	74.179	157.834	71.4526 [70]	_
B'	4.7566	_	_	_
Eg	3.38	4.09	_	3.35 [70] ^a
O				4.11 [70] ^b
				6.60 [70] ^c

Experiment ([25], [28], [30], [36], [52], [54-61], [65-67])

Ref [53] using FP-LAPW-LDA

Ref [54] using FP-LMTO-GGA + LDA

Ref [59] using PAW-GGA

Ref [62] ab initio perturbed ion (ai PI)

Ref [63] using a priori calculation

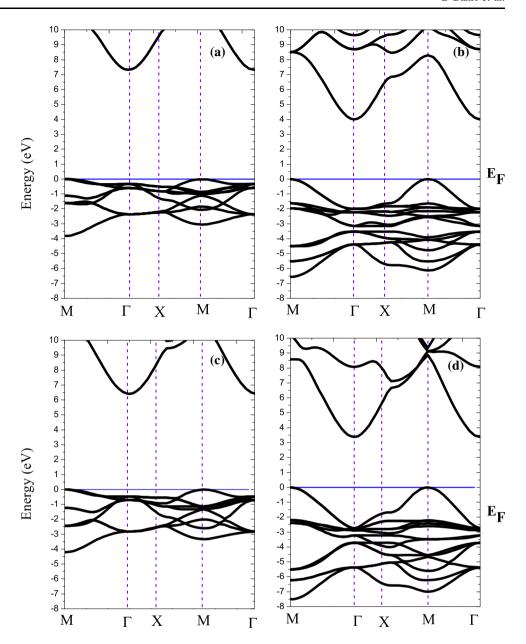
Ref [64] using PP-PW-LDA

Ref [70]^a using FP-LAPW -GGA

Ref [70]^b using FP-LAPW -EV-GGA

Ref [70]^c using FP-LAPW-mBJ

Fig. 2 Band structure for highsymmetry directions in the Brillouin zone, (a) KMgF₃, (b) KZnF₃, (c) NaMgF₃ and (d) NaZnF₃



plane wave (NCP) method within the density functional theory (DFT) with the generalized gradient approximation (GGA). The paper is organized as follows. The theoretical background is presented in Sect. 2. Results and discussion are presented in Sect. 3. A summary of the results is given in Sect. 4.

2. Computational method

Full-relativistic calculations of the electronic structure of $ABF_3(A = K, Na; B = Mg, Zn)$ are performed within the density functional theory [43] using Ab initio full-potential linearized augmented plane wave method [44] as implemented in WIEN2 K code Blaha et al. [45]. The Kohn-

Sham equations are solved self-consistently using FP-LAPW method. In the calculations reported here, we use a parameter $R_{\rm MT}K_{\rm max}=9$, which determines matrix size (convergence), where $K_{\rm max}$ is the plane wave cut-off and $R_{\rm MT}$ is the smallest of all atomic sphere radii. The radii $R_{\rm MT}$ of the muffin tins (MT) are chosen to be approximately proportional to the corresponding ionic radii. Exchange–correlation effects are treated using GGA as parameterized by Perdew et al. [46]. Self-consistent calculations are considered to be converged when the total energy of the system is stable within 10^{-4} Ry. The convergence criteria for total energy and force are taken as 10^{-5} and 10^{-4} eV/Å, respectively. The valence wave functions inside the spheres are expanded up to $l_{\rm max}=10$ while the charge density was Fourier expanded up to $G_{\rm max}=14$. The Monkorst-Pack

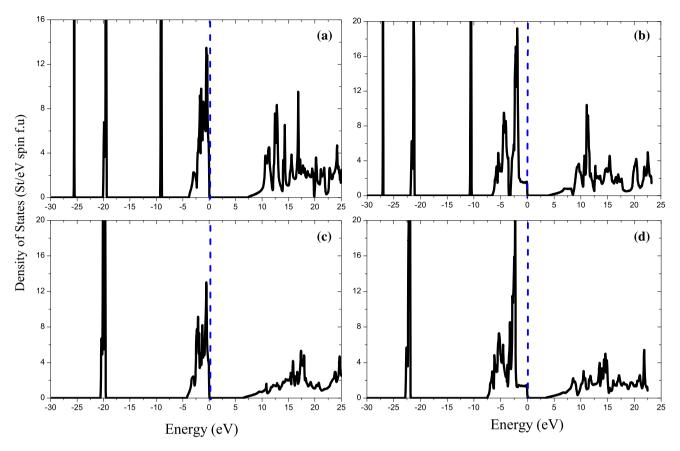


Fig. 3 Total density of states of (a) KMgF₃, (b) KZnF₃, (c) NaMgF₃ and (d) NaZnF₃

special k-points were performed using 3000 special k-points in the Brillouin zone. Calculations of the frequency-dependence of the optical properties were carried out using 8000 k-points in the Brillouin zone for the ABF_3 (A=K, Na; B=Mg, Zn) compounds.

Optical properties of a solid are usually described in terms of the complex dielectric function $\varepsilon(w) = \varepsilon_I(w) + i\varepsilon_2(w)$ The imaginary part $\varepsilon_2(w)$ was calculated from the momentum matrix elements between the occupied and unoccupied wave functions within the selection rules. The real part $\varepsilon_I(w)$ of the dielectric function was calculated by the Kramers–Kronig transformation [47] of the imaginary part $\varepsilon_2(w)$ Other optical constants were computed from the values of $\varepsilon_I(w)$

The norm-conserving pseudopotential (NCP) method [48] and the GGA approach according to Perdew-Burke-Ernzerhof [46] has been untilized in the present study. A computer program CASTEP (Cambridge Serial Total Energy Package) [49], was used tocalculate structural, electronic and optical properties of ABF $_3$ (A = K, Na; B = Mg, Zn) compounds. Besides, the kinetic cut-off energy for the plane wave expansion is considered to be 800 eV for all analyzed cases. The special points sampling integration over the Brillouin zone was employed by using the Monkhorst–Pack method with $20 \times 20 \times 20$ k-points.

Based on the Broyden Fletcher Goldfarb Shenno (BFGS) [50] minimization technique, the system reached the ground state via self-consistent calculation when the total energy is stable to within 5×10^{-6} eV/atom, and less than 10^{-2} eV/Å for the force.

3. Results and discussion

3.1. Structural properties

The main objective in this work is to calculate the total energy as a function of the unit-cell volume around the equilibrium cell volume V_0 in ABF₃(A = K, Na; B = Mg, Zn) compounds, using FP-LAPW and PP-PW methods. Figure 1 presents the structural optimization curves obtained by using the FP-LAPW method; the results indicate that KZnF₃ compound is found to be energetically more favorable than KMgF₃, NaMgF₃ and NaZnF₃ compounds. Table 1 presents the calculated equilibrium lattice constants for the ABF₃(A = K, Na; B = Mg, Zn) compounds that are determined by fitting the total energy as a function of volume to the Murnaghan equation of state [51]. Moreover, in Table 1, our calculated values of a_0 , B, and B' are compared with previous experimental and theoretical results. Based on

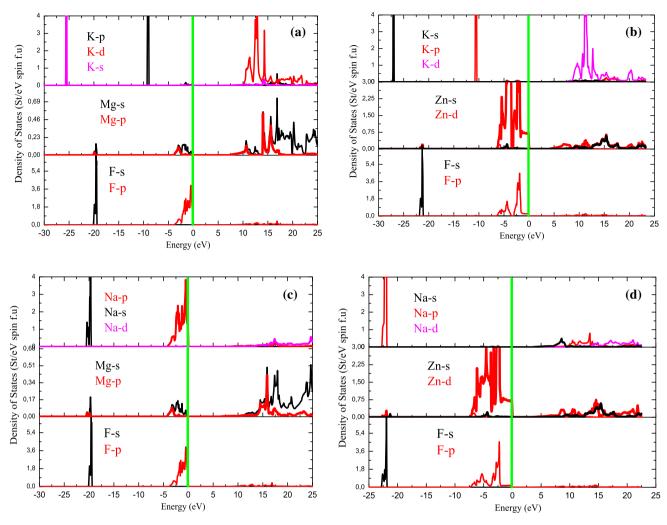


Fig. 4 Projected density of states of (a) KMgF₃, (b) KZnF₃, (c) NaMgF₃ and (d) NaZnF₃

the experimental data, the equilibrium lattice constants for KMgF₃, KZnF₃ and NaMgF₃ are best described by FP-LAPW, compared with the PW-PP method. Nevertheless, both used methods overestimated the lattice constant with respect to experiment. This is not surprising; the results are consistent with the general trend of the GGA approach [68, 69]. For the KMgF₃compound, the calculated bulk modulus by FP-LAPW is in better agreement with the experiment compared to that obtained by PP-PW. Knowing that the structural stability, mechanical, electronic and thermodynamic properties of NaXF₃ (X = Mg, Zn) compounds that was predicted by Arar et al. [70].

3.2. Electronic properties

The band structures of ABF_3 (A = K, Na; B = Mg, Zn) have been calculated at the theoretical equilibrium lattice constant using both FP-LAPW and PP-PW methods. Because of the similarity in the most estimated results, only FP-LAPW results are presented. The energy band structure

calculated along the high symmetry directions in the Brillouin zone, is illustrated in Fig. 2. The valence band maximum (VBM) is located at the *M* point, whereas the conduction band minimum (CBM) is located at the *Γ* point. The energy gap values obtained from the FP-LAPW approach are 7.37, 6.40, 4.06 and 3.38 eV, while those obtained from the PP-PW calculations are 7.56, 6.39, 4.43 and 4.09 eV, for KMgF₃, NaMgF₃, KZnF₃ and NaZnF₃, respectively. This band structure is representative of wide gap fluoroperovskite with indirect gaps insulator. For KMgF₃, the calculated indirect band gap for both methods, which is much smaller than the measured experimental value of 12.4 eV [25] (a well-known deficiency of DFT approach), however, in good agreement with the previously reported calculated values at 7.24 eV [53] and 7.03 eV [59].

In the next stage, we presented the partial densities of states of these compounds as illustrated in Figs. 3 and 4. The Fermi level was set as 0 eV. Basically, for KMgF₃ and KZnF₃ compounds, the DOS can be divided into three parts, at lower energy where we find the contribution of K-s and

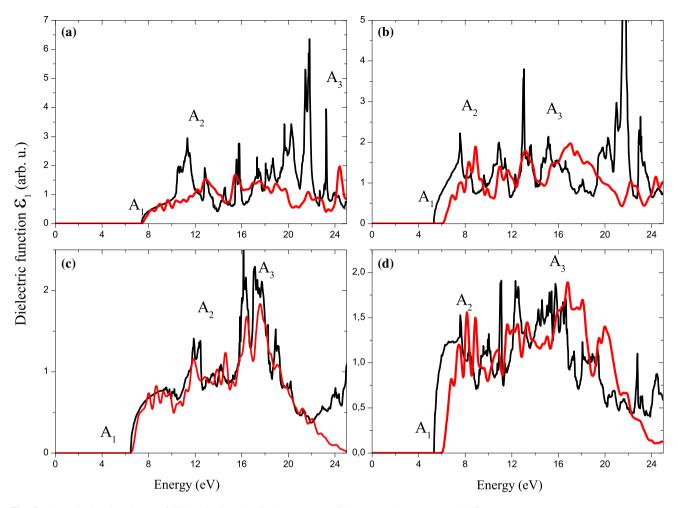


Fig. 5 The calculated real part of dielectric function for (a) KMgF3, (b) KZnF3, (c) NaMgF3 and (d) NaZnF3

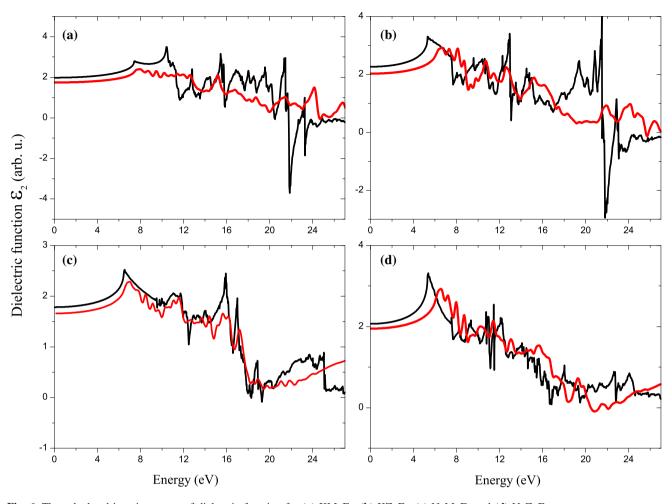
F-s states; the second part is from -15 to 0 eV that is mainly derived from K-p and F-p states for KMgF₃ compound, and K-s, Zn-d and F-p electrons for KZnF₃ compound, the third part which is beyond the Fermi level, where the contribution is due to K-d and Zn-s states for KZnF3 compound, where the K-d, s and p orbitals of Mg atoms create fully unoccupied bands for KMgF₃ compound. Furthermore, for the NaMgF₃ and NaZnF₃, a few F-s and Na-s states observed to occur at lower energies. The contribution of Zn-d and F-p states for NaZnF₃appears from -15 eV to 0 eV and the conduction band is mainly derived from Na-d and Zn-s states. It has been seen for the NaMgF₃ compound, from -15.0 to 0 eV, which represents the contribution of the p orbitals of Na atoms hybridized with F-p states and the conduction band, is mainly derived from Na d states hybridized with s and p electrons for Mg atoms.

3.3. Optical properties

Mainly, the dielectric function, refractive index and extinction coefficients at the equilibrium lattice constant

were calculated using both FP-LAPW and PP-PW approaches.

In Fig. 5 and 6 we present the dielectric function of $ABF_3(A = K, Na; B = Mg, Zn)$ compounds that calculated by FP-LAPW(black line) and PP-PW (red line) methods, respectively. For energies up to 25 eV, based on our calculated band structure it would be worthwhile to identify the interband transitions that are responsible for the structure in $\varepsilon_2(\omega)$ Our analysis of the $\varepsilon_2(\omega)$ spectra shows that the threshold energy (first critical point) of the dielectric function occurs at about A₁ (Table 2) forKMgF₃ and NaMgF₃compounds. These points are mainly initiated from the electron transition from the F-p (VB) and Na- p (VB) to Mg- p (CB) orbitals. One can note that in KMgF₃ and NaMgF₃ compounds, the ε_2 (ω) spectrum shows a peaks A₂ and A₃ (Fig. 5), respectively. These peaks are mainly derived from the transition from K-p (VB) to Mg-p(CB) and F-s (VB) and Na-s (VB) to Mg-s (CB) orbitals, respectively. In the case of KZnF₃ and NaZnF3 compounds, the peaks are A1, A2 and A3 (Fig. 5) which are mainly derived from the transition



 $\textbf{Fig. 6} \ \ \text{The calculated imaginary part of dielectric function for (a) } \ \ \text{KMgF}_3, \ \textbf{(b)} \ \ \text{KZnF}_3, \ \textbf{(c)} \ \ \text{NaMgF}_3 \ \ \text{and} \ \textbf{(d)} \ \ \text{NaZnF}_3$

Table 2 Position of the principal peaks of the imaginary part of the dielectric function for $ABF_3(A = K, Na; B = Mg, Zn)$ compounds

A1 A2 A3 $KMgF_3$ FP-LAPW 7.15 11.32 21.71 PW-PP 7.18 12.87 24.33 NaMgF₃ 12.29 FP-LAPW 6.17 17.24 PW-PP 6.27 12.00 17.63 KZnF₃ FP-LAPW 5.24 7.55 15.03 PW-PP 6.01 8.82 16.88 NaZnF₃ FP-LAPW 5.13 7.56 15.63 PW-PP 6.11 8.15 16.98

from Zn-d (VB) and F-p(VB) to K-d (CB), K-s(VB) to K-d(CB) and F-s(VB)and Na-d (VB) to K-d(CB) orbitals, respectively. The behaviour of ε_I (ω) seems to be rather similar to that of ε_2 (ω) below the reststrahlen

Table 3 Calculated, experimental and theoretical values of static constants ε_0 , refractive index n_0

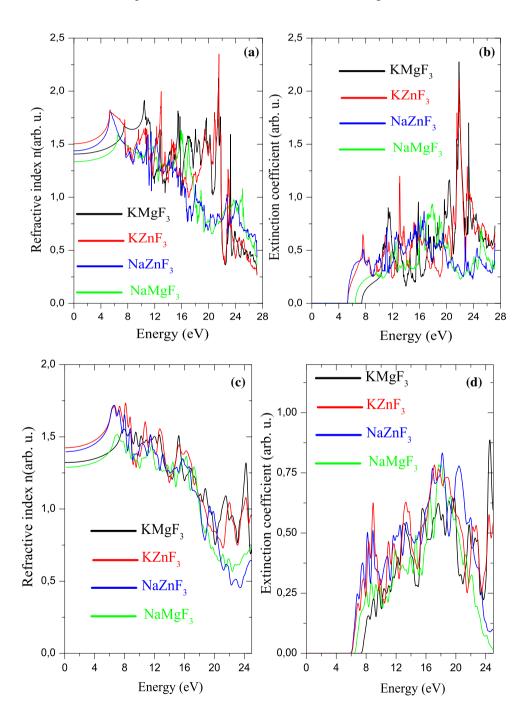
	-	_			
	Methods	Present work ε_0	Experiment ε_0	Other ε_0	Present work n (0)
KMgF ₃	FP- LAPW	1.98	2.04 [70]	2.14 [59]	1.40
	PW-PP	1.74	_	_	1.30
NaMgF ₃	FP- LAPW	1.78	-	-	1.32
	PW-PP	1.65	_	_	1.28
$KZnF_3$	FP- LAPW	2.26	-	-	1.44
	PW-PP	2.02	_	_	1.42
NaZnF ₃	FP- LAPW	2.07	-	-	1.50
	PW-PP	1.95	-	-	1.39

region in the optical spectra, the real part of the dielectric function asymptotically approaches the static or low-frequency dielectric constant ε_0 . The calculated

dielectric constant ε_0 and the static refractive index n_0 of these compounds using FP-LAPW and PP-PW methods are reported in Table 3. The present investigation shows that the dielectric constant ε_0 of the studied compounds varies from 1.74 to 2.26. Our results for the dielectric constant ε_0 of KMgF₃ compound for both methods are in good agreement with previous theoretical and experimental data [59, 71].

The refractive index and the extinction coefficient are displayed in Figs. 7 for FP-LAPW and PP-PW methods, respectively. Note that the calculated data show clear peaks originating from the excitonic transitions at the E_0 edges. The strongest peaks in $n(\omega)$ spectra are related mainly to the 2D exciton transition (E_1) [72]. In this context, using FP-LAPW method, the static refractive index n_0 is found to be 1.40, 1.32, 1.44 and 1.50 for KMgF₃, NaMgF₃, KZnF₃ and NaZnF₃ compounds. These values differ largely from those of 1.30, 1.28, 1.42 and 1.39 obtained using PP-PW method, respectively. As a matter of fact, in the absence of both experimental and theoretical data of the refractive index and extinction coefficients for the material of interest, so to the best of our knowledge, no comment can be

Fig. 7 Calculated (**a**) refractive index n(w) using FP-LAPW, (**b**) refractive index n(w) using PP-PW, (**c**) extinction coefficient using FP-LAPW, (**b**) extinction coefficient using PP-PW method



ascribed to the accuracy of the two used methods and hence our results may serve only for a reference.

4. Conclusions

In summary, we have calculated the structural, electronic and optical properties of fluoroperovskites ABF3(A = K, Na; B = Mg, Zn) using first principle. The ground state properties of these compounds such as equilibrium lattice constant, bulk modulus demonstrated a good agreement with the experimental results. The first principles calculations were adopted to study the electronic structures of ABF3 (A = K, Na; B = Mg, Zn) compounds and the results indicated that these four compounds are indirect band gap insulator. The optical properties are analysed and the origin of some peaks in the spectra is discussed. Besides, the dielectric function ε (ω), refractive index n (ω), and extinction coefficient K (ω) for radiation up to 25 eV have also been reported and discussed.

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